

# Lab 4 Report: BJT Modeling

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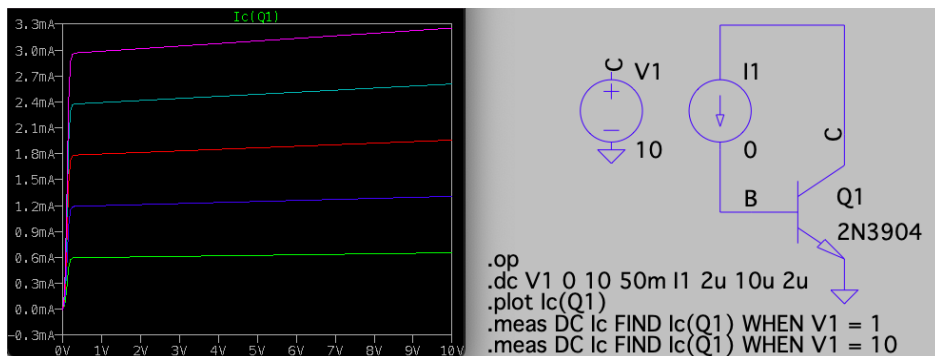
## Introduction

This lab introduces the BJT. Tasks in this lab are:

1. Simulate  $I_C$  vs.  $V_{CE}$  in LTspice using different base currents
2. Build a BJT circuit to plot observed  $I_C$  vs.  $V_{CE}$  for different base currents
3. Show the current gain at  $V_{CE} = 5V$  vs.  $I_C$
4. Estimate the Early voltage for each base current observation
5. Estimate the empirical emission coefficient  $n_F$
6. Estimate the reverse saturation current  $I_S$
7. Compare the calculations for Parts 3-6 with the manufacturer's specifications
8. Discuss the pros and cons of assuming  $V_{BE} = 0.7V$  for the forward active BJT in circuit analysis.

## 1. LTspice Simulation

Here are the plots for  $I_C$  vs.  $V_{CE}$  in LTspice:



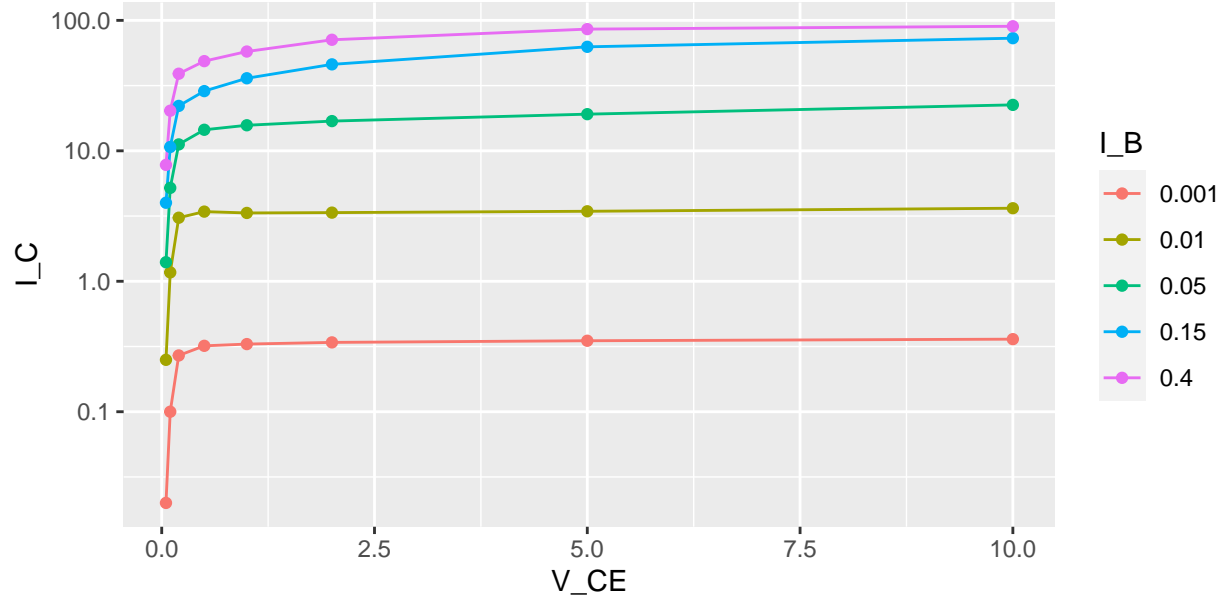
The Early voltage is calculated by saving the curves at  $V_{CE}$  at 1V and 10V:

$I_B$ ( $\mu A$ )	$I_C(V_{CE} = 1V)$ (mA)	$I_C(V_{CE} = 10V)$ (mA)	$V_A$
2	0.6012	0.6552	99.35
4	1.200	1.308	99.34
6	1.798	1.959	99.33
8	2.393	2.608	99.32
10	2.987	3.255	99.32

The calculated gain using  $\Delta I_B$  for the  $I_C$  simulated values at  $V_{CE} = 5V$ :

$I_B$ ( $\mu A$ )	$\Delta I_B$ ( $\mu A$ )	$\Delta I_C(V_{CE} = 5V)$ (mA)	$\beta$
4	2	0.6231	1.308
6	2	0.6212	1.959
8	2	0.6193	2.608
10	2	0.6175	3.255

## 2. Measured $I_C$ for $I_B$ and $V_{CE}$



## 3. Current gain estimate

Using  $\beta = \Delta I_C / \Delta I_B$  given the measured data at  $V_{CE} = 5V$  (for  $I_B \leq 50\mu A$  to avoid large current effects):

$\Delta I_B$ ( $\mu A$ )	$\Delta I_C$ (mA)	$\hat{\beta}$
10 – 1	3.44 – 0.35	343
50 – 10	19.1 – 3.44	391

## 4. Early voltage calculation

Using the range  $V_{CE}$  from 1V to 10V, I have these two estimates for the Early voltage:

$I_B$ ( $\mu A$ )	$\hat{V}_A$
10	$1V - 9V \frac{0.33}{0.93} = -98.0$
50	$1V - 9V \frac{3.34}{0.29} = -102.7$

## 5. Empirical emission coefficient

The empirical emission coefficient is between 1 and 2, there values closer to 1 appear on ICs and to 2 for discrete diodes.

$I_B$ ( $\mu A$ )	$I_C$ ( $mA$ )	$V_{BE}$ when $V_{CE} = 5V$
2	0.70	0.601
4	1.41	0.626

The calculation for  $n_F$  proceeds in the following:

$$\frac{1.41}{0.70} = \frac{I_S \exp(0.626/(n_F V_T))}{I_S \exp(0.601/(n_F V_T))}$$

$$\ln(2.0143) = \exp(0.025/(n_F V_T))$$

yielding  $n_F = 1.37$ .

## 6. Reverse saturation current $I_S$

Using  $n_F = 1.37$  in the previous formulae gives  $I_S = 32.9pA$  which is a very large value for  $I_S$ .

## 7. Listed values on 2N3904 LTspice model

.model 2N3904 NPN(IS=1E-14 VAF=100 + Bf=300 IKF=0.4 XTB=1.5 BR=4 CJC=4E-12 CJE=8E-12 RB=20 RC=0.1 RE=0.1 + TR=250E-9 TF=350E-12 ITF=1 VTF=2 XTF=3 Vceo=40 Icrating=200m mfg=NXP)

My estimate for  $\beta$  is 367, close to the LTspice value of 300. Even more impressive is the estimate for  $V_A$  of 100.4, minorly off from the LTspice value of 100. My  $I_S$  estimate is off by three orders of magnitude though.

## 8. Using a constant value for $V_{BE}$

The biggest pro for this simplification is that the schematic analyses greatly simplify. Another pro is that the simplification is justified in that every  $36mV$  (using  $n_F = 1.37$ ) the collector current multiplies by 2.718, so keeping  $I_C$  in a given range that doesn't vary broadly will constrain the base-emitter voltage to a limited range. A con for this simplification is that a  $83mV$  change in base-emitter voltage ( $n_F = 1.37$ ) yields a 10x change in collector current, so unless the current range is known, the base-emitter voltage could be incorrect by over 100mV, and that magnitude could throw off the analysis accuracy.